查询2SB1394供应商





PNP/NPN Epitaxial Planar Silicon Transistors

2SB1394/2SD2099

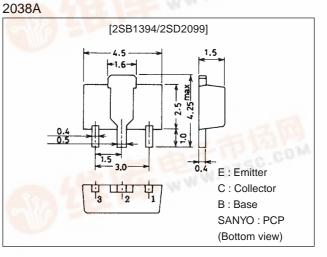
Compact Motor Driver Applications

Features

- \cdot Contains input resistance (R₁), base-to-emitter resistance (R_{BE}).
- \cdot Contains diode between collector and emitter.
- · Low saturation voltage.
- · Large current capacity.
- Small-sized package making it easy to provide highdensity, small-sized hybrid ICs.

Package Dimensions

unit:mm



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Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|--|-------------|------|
| Collector-to-Base Voltage | VCBO | | (-)40 | V |
| Collector-to-Emitter Voltage | VCEO | | (-)30 | V |
| Emitter-to-Base Voltage | V _{EBO} | | (–)6 | V |
| Collector Current | ΙC | | (-)3 | А |
| Collector Current (Pulse) | ICP | | (–)5 | A |
| Collector Dissipation | PC | Mounted on ceramic board (250mm ² ×0.8mm) | 1.5 | W |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at $Ta = 25^{\circ}C$

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---|----------------------|---|---------|---------|---------|------|
| | | | min | typ | max | |
| Collector Cutoff Current | I _{CBO} | V _{CB} =(-)30V, I _E =0 | | | (–)1.0 | μΑ |
| DC Current Gain | h _{FE} 1 | V _{CE} =(-)2V, I _C =(-)0.5A | (–)70 | | | |
| | h _{FE} 2 | V _{CE} =(-)2V, I _C =(-)2A | (–)50 | - | 12 | 111 |
| Gain-Bandwidth Product | fT | V _{CE} =(-)2V, I _C =(-)0.5A | - | 100 | 2 2 2 2 | MHz |
| Output Capacitance | Cob | V _{CB} =(-)10V, f=1MHz | | (55)40 | 5.0-1 | pF |
| Collector-to-Emitter Saturation Voltage | V _{CE(sat)} | I _C =(-)1A, I _B =(-)50mA | in M | 0.12 | 0.3 | V |
| | | | 100 | (-0.18) | (-0.4) | V |

Marking : 2SB1394 : BN

2SD2099 : DL

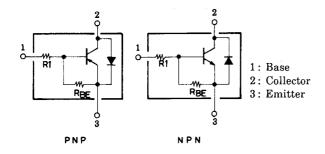
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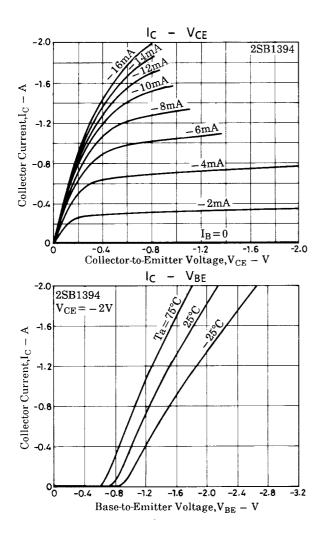
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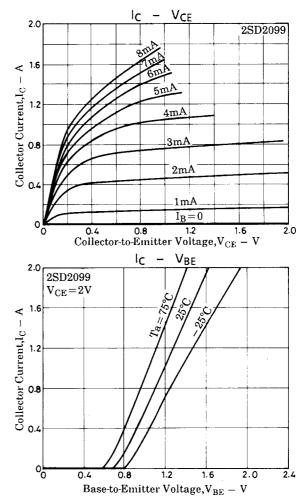
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| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|---------------------|---|---------|--------|--------|------|
| | Symbol | | min | typ | max | |
| Base-to-Emitter ON State Voltage | V _{BE(ON)} | V _{CE} =(-)2V, I _C =(-)1A | (-)0.7 | (–)1.5 | (–)4.0 | V |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | I _C =(-)10µA, I _E =0 | (–)40 | | | V |
| Collector-to-Emitter Breakdown Voltage | V(BR)CEO1 | I _C =(−)10μA, R _{BE} =∞ | (–)40 | | | V |
| | V(BR)CEO2 | I _C =(−)10mA, R _{BE} =∞ | (–)30 | | | V |
| Diode Forwad Voltage | VF | I _F =0.5A | | | (–)1.5 | V |
| Base-to-Emitter Resistance | R _{BE} | | | 0.8 | | kΩ |
| Base Resistance | R ₁ | | 60 | 90 | 120 | Ω |

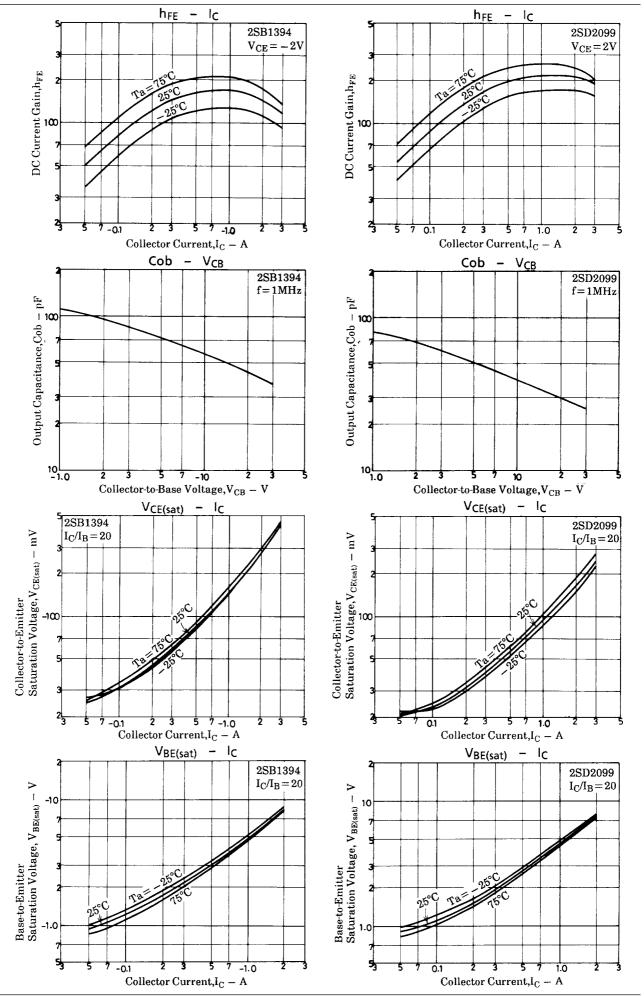
Electrical Connection



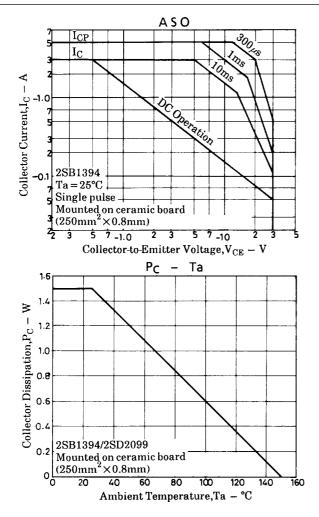


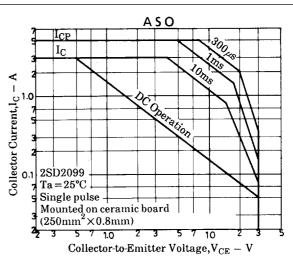


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